# ASSINGMENT 2 MICROELECTRONIC CIRCUITS DATE- 17/04/2022

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### Question 1:-

### 1 Problem-1

Cascode MOSFET Amplifier Design with MOSFET cascode load: Design a Cascode amplifier using suitable topology to meet the specifications prescribed for you. VDD is 3.3V.

Design Specifications	Specifications desired	Specifications achieved
Voltage Gain	85± 5% (V/V)	81.1637 (V/V)
Current Gain	Not applicable	Not applicable
3-dB frequency	Not applicable	Not applicable
Pd	2.0± 5% (mW)	2.0702 (mW)

ID used for calculation:- 2020A3PS1237P

Sum of last 2 digits = 3+7 = 10

10 % 4 = 2. Hence the required specifications were taken from Table 1.

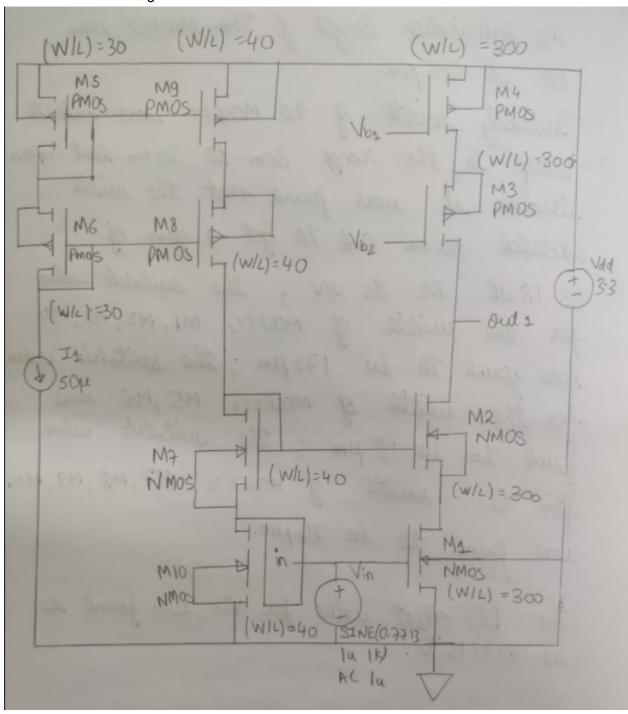
The fabrication length of MOSFET was set at 0.6 micrometer.

Initially width of MOSFET was made to sweep in the range 3 nm to 30 nm but upon iteration it was found out that the width exceeded 30 nm and to get a gain of 38.18 dB or 81.1637 (V/V), the suitable value for the width of MOSFETs M1,M2,M3,M4 = 180 micrometer the suitable value for the width of MOSFETs M7,M8,M9,M10 = 24 micrometer the suitable value for the width of MOSFETs M5,M6 = 18 micrometer

DC offset value for Vin was found to be 0.7713 V.

MOSFET Name	MOSFET w/I
M1	300
M2	300
M3	300
M4	300
M5	30
M6	30
M7	40
M8	40
M9	40
M10	40

Hand drawn circuit diagram-



```
Vollage Swing calculation:
      For NMOS, VTH = 0.6696061 (Thrushold voltage)
      For PMOS, VIH = -0.9214347 (Tweshold voltage)
Following values are taken by running of command =>
For MI NMOS , IVGs = Vin - Vground
                      = 0.7713 V
                 Vovm= 1Vas1-1V7H1 = 0.7713 -0.6696061
                      = 0.1016939V
for M2 NMOS, IVUSI = Vd - Vc
                      = 1.57744- 0.81617
                       = 0.76127 V
                  Vovm= 1Vas1-1V741
= 0.76127-0.6696061
                       = 0.0916639 V
 For M3 M4 PMOS , 1V45 = Vad - Vb1
                         = 3.3 - 2.16028
                    VOVMG = 1VGS1-1VTH1
                          = 1.13172 - 0.9214847
                          = 0.2182853V
 For M3 PMOS , IVers1 = Va-Vb2
                            = 8:18 2.34723-1.02055
                            = 1.32 66 PV
                      VOV M3 = 1 V451-1 VTH1
                             = 1.32668 - 0.4214347
                              = 0.4052453V
```

Voltage swing = Voo - Vorm, - Vorme - Vorme - Vorme - Vorme = [2.4831116 V]

which comes under the permissible range of voltage swing specified.

Power consumption calculation:
Current Shrough emplifiers M1, M2, M3, M4 = 0.00050981 A

Current through emplifiers M7, M8, M9, M10 = 6.7523×10-5A

Current Shrough emplifiers M5, M6 = 5×10-5A

(These values were take by running the openment)

Sum of currents which pass through Vad

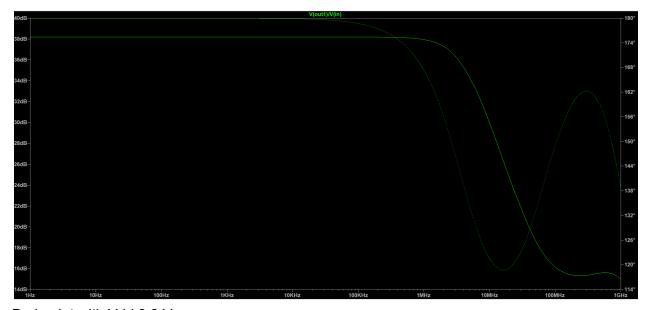
= 6.7523×10-5+5×10-5+0.00050981

= 6.2733×10-4A

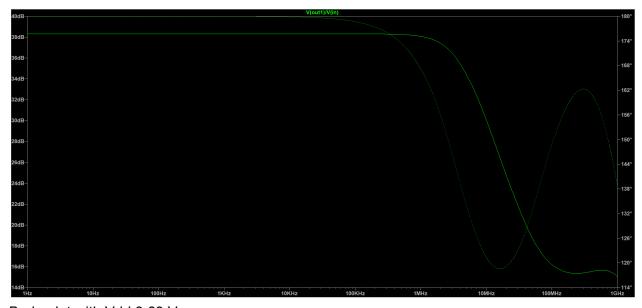
Power = 6.2733 ×10-4 × 3.3

(Power = Voltage × (werent)

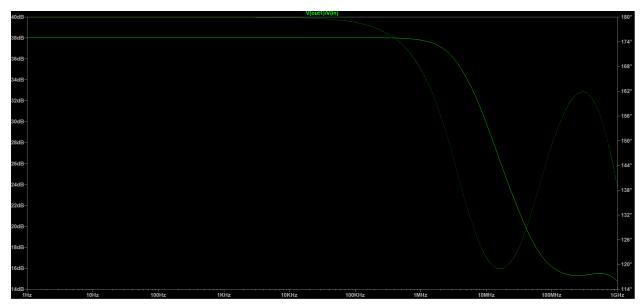
= 2.6702 × 103 W)



Bode plot with Vdd  $3.3\ V$ 



Bode plot with Vdd 3.63 V Gain when Vdd is changed to Vdd+10%(3.63 V) is 38.320195dB.



Bode plot with Vdd 2.97V Gain when Vdd is changed to Vdd-10%(2.97 V) is 38.03741dB

Operating Point			
V(c):	0.810876	voltage	
V(in):	0.7713	voltage	
V(out1):	1.92198	voltage	
V(d):	1.57685	voltage	
V(a):	2.03032	voltage	
V(vb2):	0.690554	voltage	
V(n001):	2.97	voltage	
V(vb1):	1.83028	voltage	
V(e):	0.788424	voltage	
V(f):	1.86826	voltage	
Id(M9):	6.72423e-005	device current	
Ig(M9):	-0	device current	
Ib (M9):	1.11174e-012	device current	
Is(M9):	-6.72423e-005	device current	
Id(M8):	6.72423e-005	device current	
Ig(M8):	-0	device current	
Ib (M8):	3.01415e-013	device current	
Is(M8):	-6.72423e-005	device current	
Id(M6):	5e-005	device current	
Ig (M6):	-0	device current	
Ib (M6):	1.14972e-012	device current	
Is(M6):	-5e-005	device current	
Id(M5):	5e-005	device current	
Ig (M5):	-0	device current	
Ib (M5):	1.14972e-012	device current	
Is(M5):	-5e-005	device current	
Id(M4):	0.000485579	device current	
Ig (M4):	-0	device current	
Ib (M4):	9.49681e-013	device current	
Is(M4):	-0.000485579	device current	
Id(M3):	0.000485578	device current	
Ig(M3):	-0	device current	
Ib(M3):	1.18186e-013	device current	
Is(M3):	-0.000485578	device current	
Id(M10):	6.72423e-005	device current	
Ig(M10):	0	device current	
Ib (M10):	-7.98424e-013	device current	
Is(M10):	-6.72423e-005	device current	
Id(M7):	6.72423e-005	device current	
Ig(M7):	0	device current	
Ib(M7):	-7.98424e-013	device_current	
Is(M7):	-6.72423e-005	device current	
Id(M2):	0.000485579	device_current	
Ig (M2):	0	device current	
Ib (M2):	-1.12111e-012	device current	
Is(M2):	-0.000485579	device_current	
Id(M1):	0.000485579	device current	
Ig(M1):	0	device_current	
Ib(M1):	-8.20876e-013	device_current	
Is(M1):	-0.000485579	device_current	
I(I1):	5e-005	device_current	
I (Vin):	0	device_current	
I (Vdd):	-0.000602821	device_current	

# .op command for q1

### Question 2-

# 2 Problem-2

Design a (Common Base + Common Emitter) amplifier using suitable topology to meet the specifications prescribed for you. VDD is 3.3V.

Note: Other instructions remains same as previously given

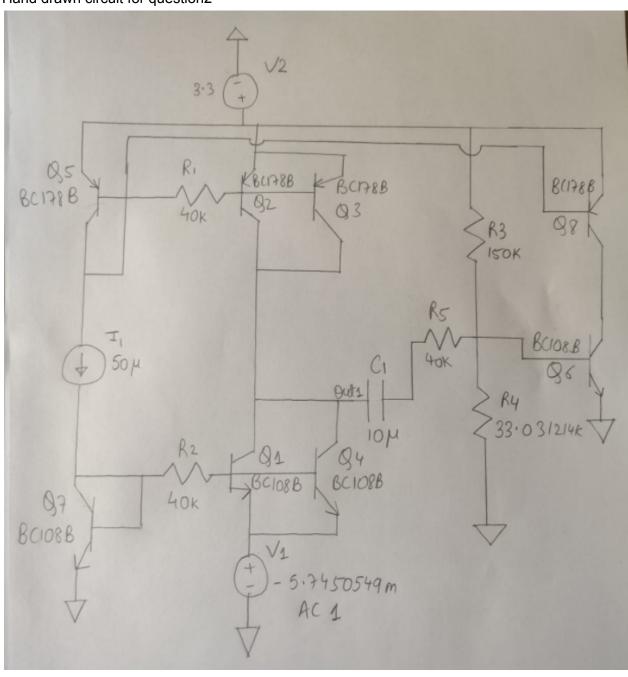
Design Specifications	Specifications desired	Specifications achieved
Voltage Gain	85± 5% (V/V)	87.5334
Current Gain	45± 5% (A/A)	24.64336
3-dB frequency	50K ± 5% (rad/s)	15.4506K (rad/s)
Pd	2.0± 5% (mW)	0.607 (mW)

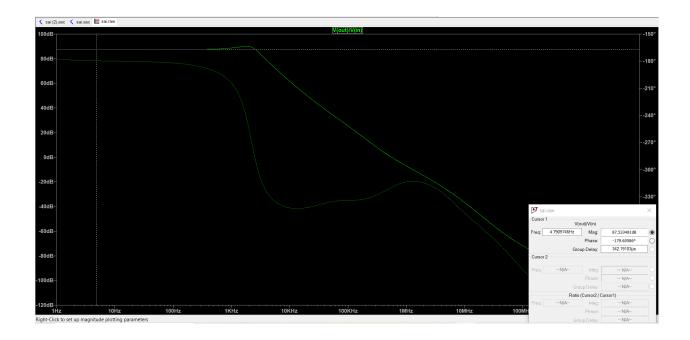
ID used for calculation:- 2020A3PS1237P

Sum of last 2 digits = 3+7 = 10

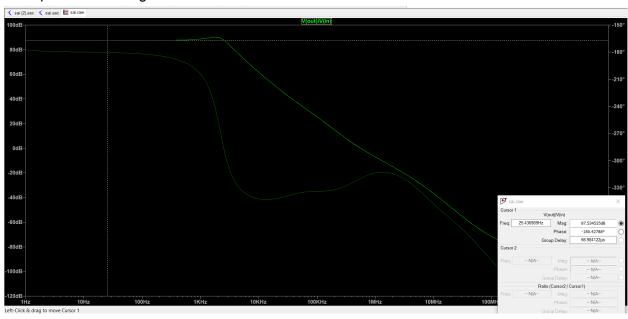
10 % 4 = 2 . Hence the required specifications were taken from Table 1.

# Hand drawn circuit for question2-

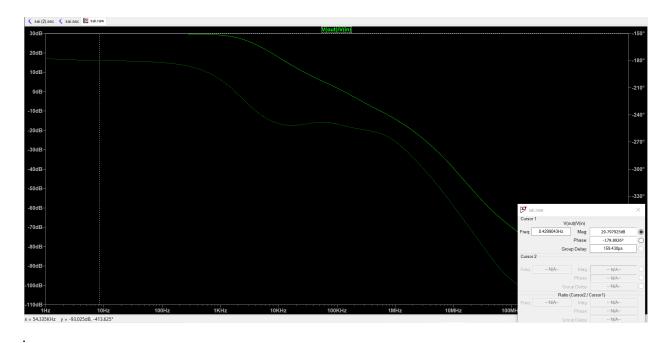




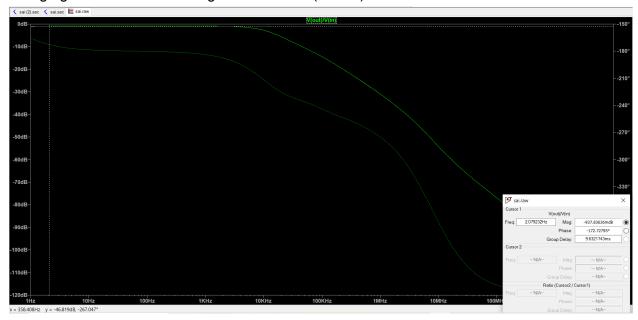
### Bode plot for current gain for Vdd 3.3 V



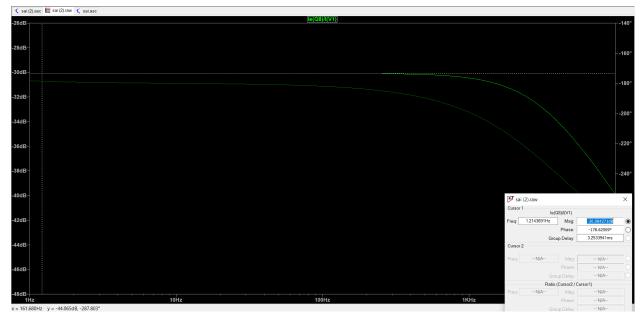
Bode plot for voltage gain with Vdd 3.63 V Voltage gain when Vdd is changed to Vdd+10%(3.63 V) is 29.797925dB.



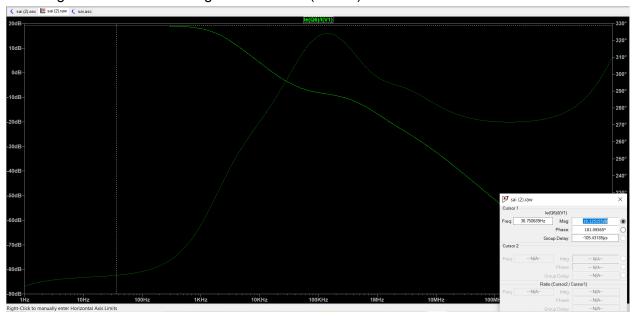
Bode plot for voltage gain with Vdd 2.97 V Voltage gain when Vdd is changed to Vdd-10%(2.97 V) is -937.83636mdB.



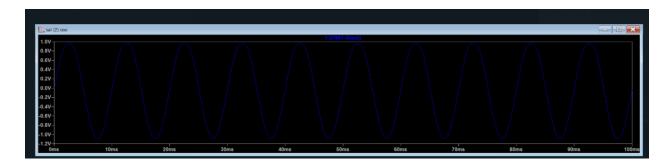
Bode plot for current gain with Vdd 3.63 V. Current gain when Vdd is changed to Vdd+10%(3.3 V) is -30.084271dB.



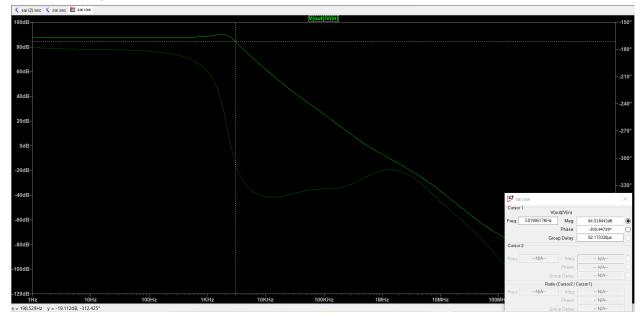
Bode plot for current gain with Vdd 2.97 V. Current gain when Vdd is changed to Vdd-10%(2.97 V) is 19.125155dB.



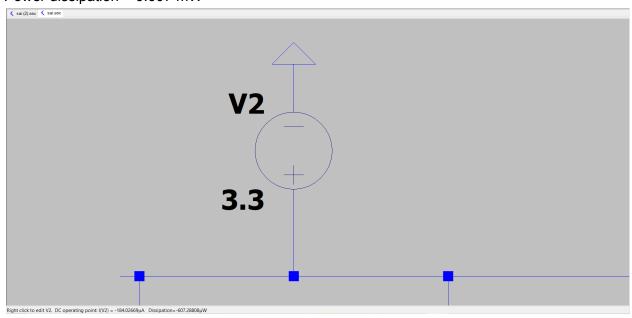
Voltage swing achieved from SPICE = 2.0312 V



# 3 dB frequency for Vdd 3.3 V = 3.013006 KHz = 18.921 K rad/s



### Power dissipation = 0.607 mW



\* C:\Users\manah\Downloads\sai.asc

<u></u>	Operating Point	-
V(out1):	1.52583	voltage
V(n006):	0.569155	voltage
V(n009):	-0.00574505	voltage
V(n003):	2.82576	voltage
V(n001):	3.3	voltage
V(n002):	2.81371	voltage
V(n005):	0.586298	voltage
V(n004):	1.40044	voltage
V(n008):	0.587096	voltage
V(n007):	0.587096	voltage
Ic(Q8):	-5.15048e-005	device_current
Ib(Q8):	-2.28588e-007	device_current
Ie (Q8) :	5.17333e-005	device_current
Ic(Q3):	-3.2218e-005	device_current
Ib(Q3):	-1.50573e-007	device_current
Ie (Q3):	3.23685e-005	device_current
Ic(Q5):	-4.92399e-005	device_current
Ib(Q5):	-2.30346e-007	device_current
Ie (Q5):	4.94703e-005	device_current
Ic(Q2):	-3.2218e-005	device_current
Ib(Q2):	-1.50573e-007	device_current
Ie (Q2):	3.23685e-005	device_current
Ic(Q6):	5.15048e-005	device_current
Ib(Q6):	3.1205 <b>4</b> e-007	device_current
Ie (Q6) :	-5.18168e-005	device_current
Ic(Q4):	3.2218e-005	device_current
Ib (Q4):	2.14286e-007	device_current
Ie (Q4):	-3.24322e-005	device_current
Ic(Q7):	4.92668e-005	device_current
Ib(Q7):	3.04607e-007	device_current
Ie(Q7):	-4.95714e-005	device_current
Ic(Q1):	3.2218e-005	device_current
Ib(Q1):	2.14286e-007	device_current
Ie (Q1):	-3.24322e-005	device_current
I(C1):	9.38731e-018	device_current
I(I1):	5e-005	device_current
I(R5):		device_current
I(R4):	1.7774e-005	device_current
I(R3):	1.8086e-005	device_current
I(R2):	-4.28571e-007	device_current
I(R1):	3.01147e-007	device_current
I(V2):	-0.000184027 6.48645e-005	device_current
I(V1):	0.40045e-UU5	device_current

### **Netlist for question 1**

```
M1 c in 0 0 NMOS I=0.6u w=172u
M2 out1 d c c NMOS I=0.6u w=172u
M3 a Vb2 out1 a PMOS I=0.6u w=172u
M4 N001 Vb1 a N001 PMOS I=0.6u w=172u
Vdd N001 0 3.3
Vin in 0 SINE(0.7713 1u 1k) AC 1u
M5 N001 Vb1 Vb1 N001 PMOS I=0.6u w=18u
M6 Vb1 Vb2 Vb2 Vb1 PMOS I=0.6u w=18u
M7 d d e e NMOS I=0.6u w=24u
11 Vb2 0 50µ
M8 f Vb2 d f PMOS I=0.6u w=24u
M9 N001 Vb1 f N001 PMOS I=0.6u w=24u
M10 e e 0 0 NMOS I=0.6u w=24u
.model NMOS NMOS
.model PMOS PMOS
.lib C:\Users\Sai Kartik\OneDrive - BIRLA INSTITUTE OF TECHNOLOGY and
SCIENCE\Documents\LTspiceXVII\lib\cmp\standard.mos
.MODEL NMOS NMOS (
                                    LEVEL = 8
+VERSION = 3.1
                   TNOM = 27
                                     TOX = 1.39E-8
+XJ
                 NCH = 1.7E17
                                   VTH0 = 0.6696061
     = 1.5E-7
+K1
      = 0.8351612
                   K2
                        = -0.0839158
                                     K3
                                           = 23.1023856
+K3B = -7.6841108 W0 = 1E-8
                                    NLX = 1E-9
+DVT0W = 0
                  DVT1W = 0
                                    DVT2W = 0
                    DVT1 = 0.4302695
+DVT0 = 2.9047241
                                        DVT2 = -0.134857
                                          = 1.485499E-18
+U0
     = 458.439679 UA
                         = 1E-13
                                    UB
      = 1.629939E-11 VSAT = 1.643993E5 A0
+UC
                                              = 0.6103537
+AGS = 0.1194608
                    B0
                         = 2.674756E-6 B1
                                            = 5E-6
+KETA = -2.640681E-3 A1
                          = 8.219585E-5 A2
                                             = 0.3564792
+RDSW = 1.387108E3 PRWG = 0.0299916
                                           PRWB = 0.0363981
+WR
                WINT = 2.472348E-7 LINT = 3.597605E-8
      = 1
+XL
               XW
                               DWG
                                      = -1.287163E-8
      = 0
                     = 0
+DWB = 5.306586E-8 VOFF = 0
                                      NFACTOR = 0.8365585
                CDSC = 2.4E-4
                                  CDSCD = 0
+CIT = 0
+CDSCB = 0
                  ETA0 = 0.0246738
                                      ETAB = -1.406123E-3
+DSUB = 0.2543458
                     PCLM = 2.5945188
                                         PDIBLC1 = -0.4282336
+PDIBLC2 = 2.311743E-3 PDIBLCB = -0.0272914
                                            DROUT = 0.7283566
+PSCBE1 = 5.598623E8
                      PSCBE2 = 5.461645E-5 PVAG = 0
                                   MOBMOD = 1
+DELTA = 0.01
                  RSH = 81.8
+PRT = 8.621
                  UTE
                       = -1
                                  KT1
                                       = -0.2501
+KT1L = -2.58E-9
                   KT2 = 0
                                  UA1
                                        = 5.4E-10
+UB1
      = -4.8E-19
                   UC1
                         = -7.5E-11
                                     AΤ
                                          = 1E5
+WL
      = 0
                WLN = 1
                               WW
                                      = 0
```

```
+WWN = 1
           WWL = 0
                        LL = 0
           LW = 0 LWN = 1
+LLN = 1
+LWL = 0
           CAPMOD = 2 XPART = 0.5
+CGDO = 2E-10
               CGSO = 2E-10
                              CGBO = 1E-9
+CJ = 4.197772E-4 PB = 0.99
                            MJ = 0.4515044
                              MJSW = 0.1153991
+CJSW = 3.242724E-10 PBSW = 0.1
+CJSWG = 1.64E-10 PBSWG = 0.1
                               MJSWG = 0.1153991
+CF = 0 PVTH0 = 0.0585501 PRDSW = 133.285505
+PK2 = -0.0299638 WKETA = -0.0248758 LKETA = 1.173187E-3
+AF = 1
            KF = 0
* .ac dec 100 1 1G
* .step param x 0.5u 13.5u 0.5u
* .step param v 0.7 0.8 0.0001
.MODEL PMOS PMOS (
                            LEVEL = 8
              TNOM = 27
                            TOX = 1.39E-8
+VERSION = 3.1
+XJ = 1.5E-7 NCH = 1.7E17
                           VTH0 = -0.9214347
+K1 = 0.5553722 \quad K2 = 8.763328E-3 \quad K3 = 6.3063558
+K3B = -0.6487362 W0 = 1.280703E-8 NLX = 2.593997E-8
+DVT0W = 0
          DVT1W = 0 DVT2W = 0
+DVT0 = 2.5131165 DVT1 = 0.5480536 DVT2 = -0.1186489
+U0 = 212.0166131 UA = 2.807115E-9 UB = 1E-21
+UC = -5.82128E-11 VSAT = 1.713601E5 A0 = 0.8430019
+AGS = 0.1328608 B0 = 7.117912E-7 B1 = 5E-6
+KETA = -3.674859E-3 A1 = 4.77502E-5 A2 = 0.3
+RDSW = 2.837206E3 PRWG = -0.0363908 PRWB = -1.016722E-5
+WR = 1 WINT = 2.838038E-7 LINT = 5.528807E-8
            XW = 0 DWG = -1.606385E-8
+XL = 0
+DWB = 2.266386E-8 VOFF = -0.0558512 NFACTOR = 0.9342488
+CIT = 0 CDSC = 2.4E-4 CDSCD = 0
                              ETAB = -0.0580325
+CDSCB = 0
              ETA0 = 0.3251882
+DSUB = 1
              PCLM = 2.2409567
                              PDIBLC1 = 0.0411445
+PDIBLC2 = 3.355575E-3 PDIBLCB = -0.0551797 DROUT = 0.2036901
+DELTA = 0.01
            RSH = 101.6
                           MOBMOD = 1
+PRT = 59.494
              UTE = -1
                           KT1 = -0.2942
+KT1L = 1.68E-9 KT2 = 0
                           UA1 = 4.5E-9
+UB1 = -6.3E-18 UC1 = -1E-10 AT = 1E3
           WLN = 1
                        WW = 0
+WL = 0
+WWN = 1
             WWL = 0
                           LL = 0
            LW = 0
+LLN = 1
                        LWN = 1
+LWL = 0
           CAPMOD = 2 XPART = 0.5
+CJ = 7.235528E-4 PB = 0.9527355
                              MJ = 0.4955293
+CJSW = 2.692786E-10 PBSW = 0.99 MJSW = 0.2958392
```

```
+CJSWG = 6.4E-11 PBSWG = 0.99 MJSWG = 0.2958392

+CF = 0 PVTH0 = 5.98016E-3 PRDSW = 14.8598424

+PK2 = 3.73981E-3 WKETA = 5.292165E-3 LKETA = -4.205905E-3

+AF = 1 KF = 0)

* power consumed = 1.93mW

* Voltage gain of the circuit= 38.18dB

* required swing = 2.66V

.backanno
```

### **Netlist for question 2**

.end

Q1 out1 N005 N008 0 BC108B Q2 out1 N003 N001 0 BC178B V1 N008 0 -5.7450549m AC 1 R1 N003 N002 40k Q5 N002 N002 N001 0 BC178B I1 N002 N004 50μ Q7 N004 N004 0 0 BC108B R2 N005 N004 40k V2 N001 0 3.3 Q3 out1 N003 N001 0 BC178B Q4 out1 N005 N008 0 BC108B Q6 out N007 0 0 BC108B Q8 out N002 N001 0 BC178B R3 N001 N007 150k R4 N007 0 33.031214K R5 N007 N006 40k C1 out1 N006 10µ C2 out 0 100f .model NPN NPN .model PNP PNP .lib C:\Users\Sai Kartik\OneDrive - BIRLA INSTITUTE OF TECHNOLOGY and SCIENCE\Documents\LTspiceXVII\lib\cmp\standard.bit .model BC107A NPN(Is=7.049f Xti=3 Eg=1.11 Vaf=116.3 Bf=375.5 Ise=7.049f Ne=1.281 lkf=4.589 Nk=.5 Xtb=1.5 Br=2.611 lsc=121.7p Nc=1.865 + Ikr=5.313 Rc=1.464 Cjc=5.38p Mjc=.329 Vjc=.6218 Fc=.5 Cje=11.5p Mje=.2717 Vje=.5 Tr=10n Tf=451p Itf=6.194 Xtf=17.43 Vtf=10) .model BC107B NPN(Is=7.049f Xti=3 Eq=1.11 Vaf=59.59 Bf=381.7 Ise=59.74f + Ne=1.522 lkf=3.289 Nk=.5 Xtb=1.5 Br=2.359 lsc=192.9p Nc=1.954 Ikr=7.807 Rc=1.427 Cjc=5.38p Mjc=.329 Vjc=.6218 Fc=.5 Cje=11.5p + Mje=.2718 Vje=.5 Tr=10n Tf=438p Itf=5.716 Xtf=14.51 Vtf=10) .model BC108A NPN(Is=7.049f Xti=3 Eg=1.11 Vaf=116.3 Bf=375.5 Ise=7.049f Ne=1.281 lkf=4.589 Nk=.5 Xtb=1.5 Br=2.611 lsc=121.7p Nc=1.865

```
Ikr=5.313 Rc=1.464 Cjc=5.38p Mjc=.329 Vjc=.6218 Fc=.5 Cje=11.5p
         Mje=.2717 Vje=.5 Tr=10n Tf=451p Itf=6.194 Xtf=17.43 Vtf=10)
.model BC108B NPN(Is=7.049f Xti=3 Eq=1.11 Vaf=59.59 Bf=381.7 Ise=59.74f
         Ne=1.522 lkf=3.289 Nk=.5 Xtb=1.5 Br=2.359 lsc=192.9p Nc=1.954
+
+
         Ikr=7.807 Rc=1.427 Cjc=5.38p Mjc=.329 Vjc=.6218 Fc=.5 Cje=11.5p
         Mje=.2718 Vje=.5 Tr=10n Tf=438p ltf=5.716 Xtf=14.51 Vtf=10)
+
.model BC178B PNP(Is=336.7f Xti=3 Eq=1.11 Vaf=30.75 Bf=271.9 Ise=2.821p
         Ne=1.925 lkf=.2462 Nk=.5416 Xtb=1.5 Br=3.009 lsc=1.753n
         Nc=2.075 lkr=8.143 Rc=1.803 Cjc=11p Mjc=.2223 Vjc=.5 Fc=.5
+
+
         Cje=33p Mje=.3333 Vje=.5 Tr=10n Tf=846p Itf=1.546 Xtf=18.27
+
         Vtf=10)
.model BC179A PNP(Is=336.7f Xti=3 Eg=1.11 Vaf=44.61 Bf=187 Ise=336.8f
         Ne=1.459 lkf=.2059 Nk=.5081 Xtb=1.5 Br=4.068 lsc=1.121n
+
         Nc=1.953 lkr=10.05 Rc=1.86 Cjc=11p Mjc=.2223 Vjc=.5 Fc=.5
         Cje=33p Mje=.3333 Vje=.5 Tr=10n Tf=845.5p Itf=1.701 Xtf=19.04
+
         Vtf=10)
+
;dc v3 -5 5 0.001
.ac dec 1000 1 10G
.op
;.step param r 30k 1000k 1k
.backanno
.end
```